

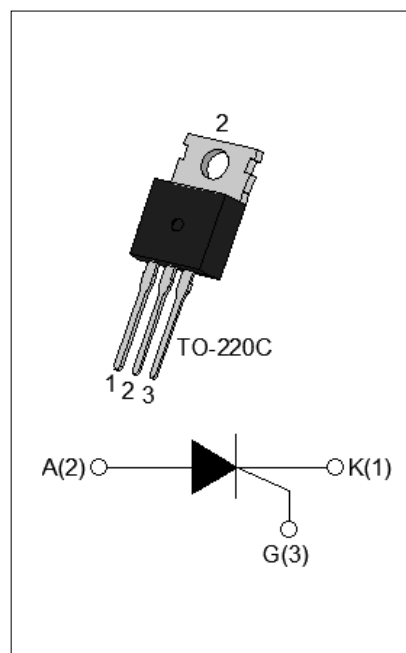


### DESCRIPTION:

With high ability to withstand the shock loading of large current, JCT1225C SCR provides high  $dV/dt$  rate with strong resistance to electromagnetic interference. It is especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc. Package TO-220C is RoHS compliant.

### MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	25	A
$V_{DRM}/V_{RRM}$	1200	V
$I_{GT}$	$\leq 40$	mA



### ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	$^{\circ}C$
Operating junction temperature range	$T_j$	-40-125	$^{\circ}C$
Repetitive peak off-state voltage ( $T_j=25^{\circ}C$ )	$V_{DRM}$	1200	V
Repetitive peak reverse voltage ( $T_j=25^{\circ}C$ )	$V_{RRM}$	1200	V
Average on-state current ( $T_c \leq 96^{\circ}C$ )	$I_{T(AV)}$	16	A
RMS on-state current ( $T_c \leq 96^{\circ}C$ )	$I_{T(RMS)}$	25	A
Non repetitive surge peak on-state current ( $t_p=10ms, T_j=25^{\circ}C$ )	$I_{TSM}$	320	A
Non repetitive surge peak on-state current ( $t_p=8.3ms, T_j=25^{\circ}C$ )		352	
$I^2t$ value for fusing ( $t_p=10ms, T_j=25^{\circ}C$ )	$I^2t$	512	$A^2s$
Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}, f=100Hz, T_j=125^{\circ}C$ )	$di/dt$	200	$A/\mu s$
Peak gate current ( $t_p=20\mu s, T_j=125^{\circ}C$ )	$I_{GM}$	5	A
Average gate power dissipation ( $T_j=125^{\circ}C$ )	$P_{G(AV)}$	1	W

Peak gate power	$P_{GM}$	20	W
Peak pulse voltage ( $T_j=25^{\circ}C$ ; non-repetitive, off-state; FIG.7)	$V_{pp}$	1	kV

**ELECTRICAL CHARACTERISTICS** ( $T_j=25^{\circ}C$  unless otherwise specified)

Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
$I_{GT}$	$V_D=12V R_L=33\Omega$	-	-	40	mA
$V_{GT}$		-	-	1	V
$V_{GD}$	$V_D=V_{DRM} T_j=125^{\circ}C R_L=3.3K\Omega$	0.2	-	-	V
$I_L$	$I_G=1.2I_{GT}$	-	-	90	mA
$I_H$	$I_T=500mA$	-	-	80	mA
dV/dt	$V_D=800V$ Gate Open $T_j=125^{\circ}C$	1000	-	-	V/ $\mu s$
$t_{on}$	$I_G=50mA I_A=500mA I_R=50mA$ $T_j=25^{\circ}C$	-	5	-	$\mu s$
$t_{off}$		-	70	-	

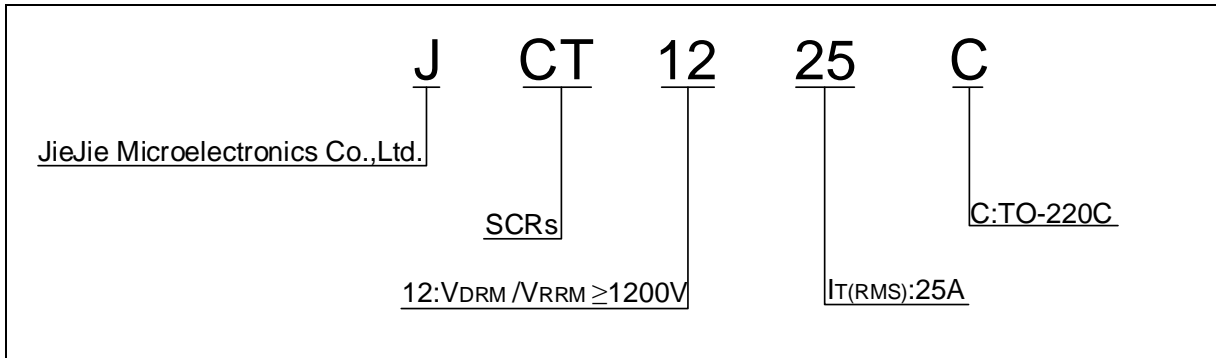
**STATIC CHARACTERISTICS**

Symbol	Parameter	Value(MAX.)	Unit
$V_{TM}$	$I_{TM}=50A t_p=380\mu s$ $T_j=25^{\circ}C$	1.55	V
$V_{TO}$	Threshold voltage $T_j=125^{\circ}C$	0.74	V
$R_D$	Dynamic resistance $T_j=125^{\circ}C$	19	m $\Omega$
$I_{DRM}$	$V_D=V_{DRM} V_R=V_{RRM}$	$T_j=25^{\circ}C$	7 $\mu A$
$I_{RRM}$		$T_j=125^{\circ}C$	2 mA

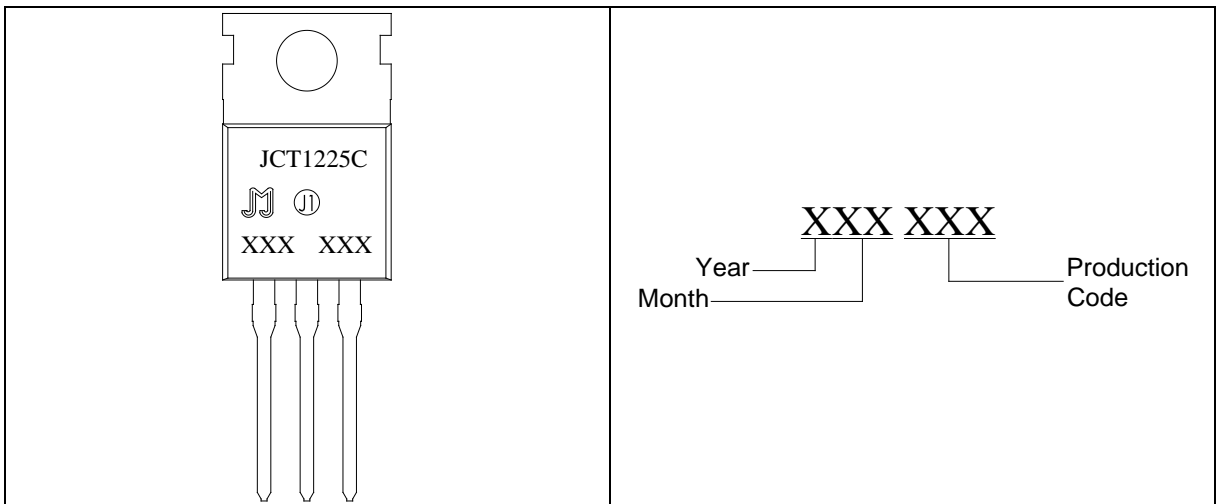
**THERMAL RESISTANCES**

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case(DC)	0.9	$^{\circ}C/W$
$R_{th(j-a)}$	junction to ambient (DC)	45	$^{\circ}C/W$

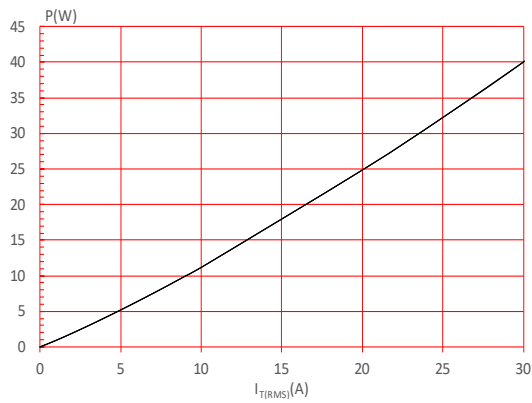
**ORDERING INFORMATION**



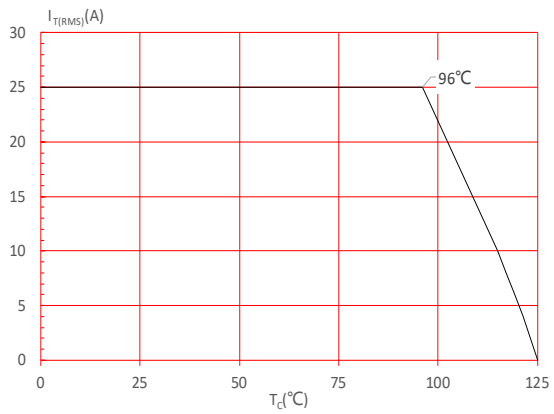
**MARKING**



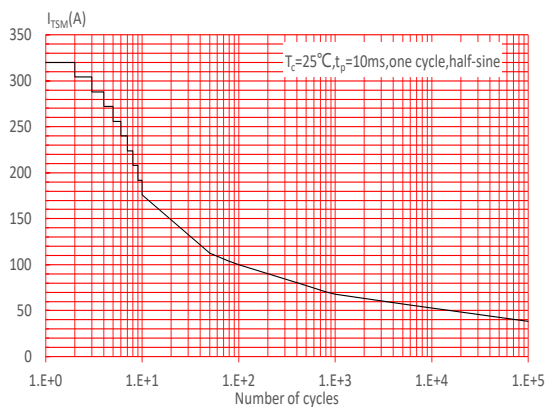
**FIG.1** Maximum power dissipation versus RMS on-state current



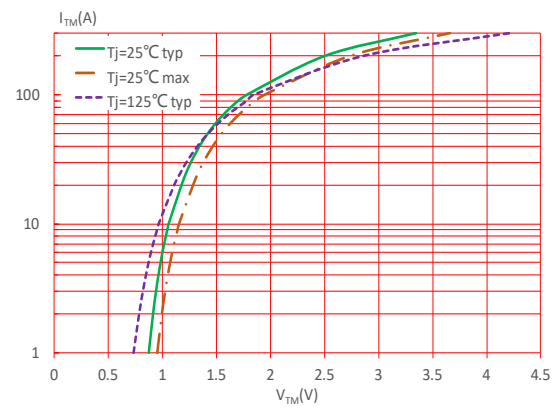
**FIG.2:** RMS on-state current versus case temperature



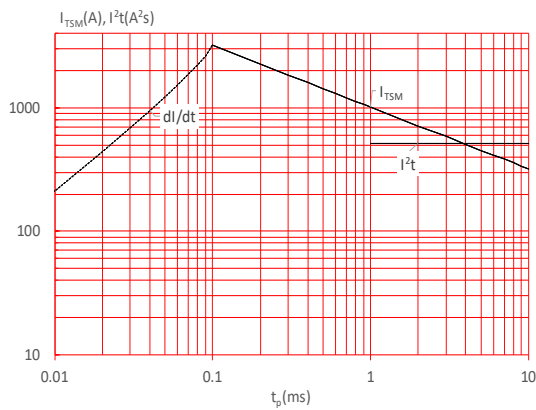
**FIG.3:** Surge peak on-state current versus number of cycles



**FIG.4:** On-state characteristics



**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10\text{ms}$ , and corresponding value of  $I^2t$  ( $di/dt < 200\text{A}/\mu\text{s}$ )



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

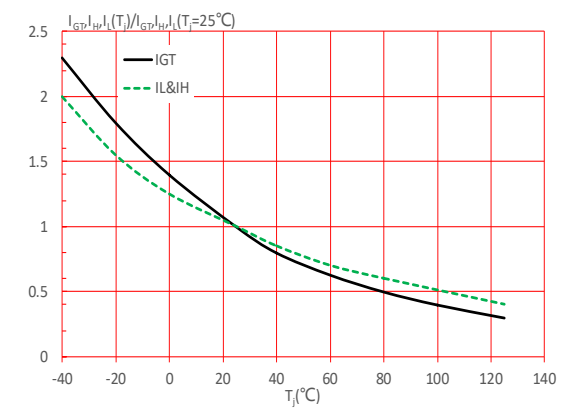
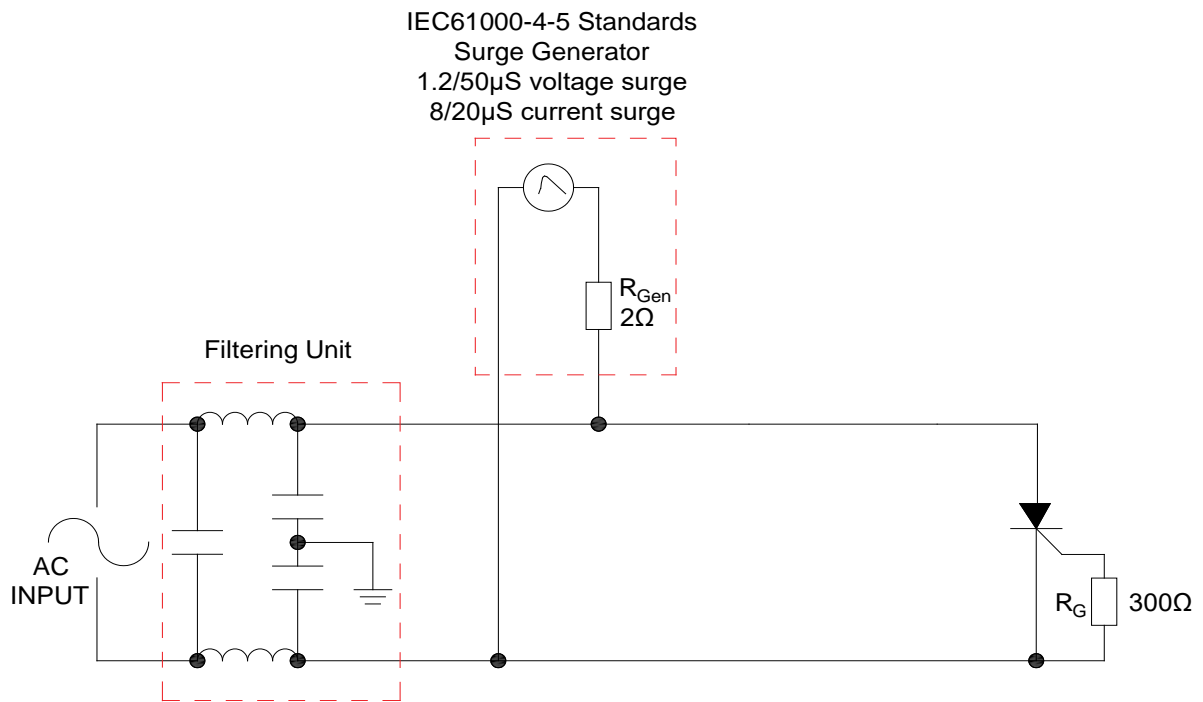


FIG.7: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards.



## SHAPING AND SOLDERING PARAMETERS

Refer to «Instructions for installation of plastic-sealed in-line power devices» released by JieJie

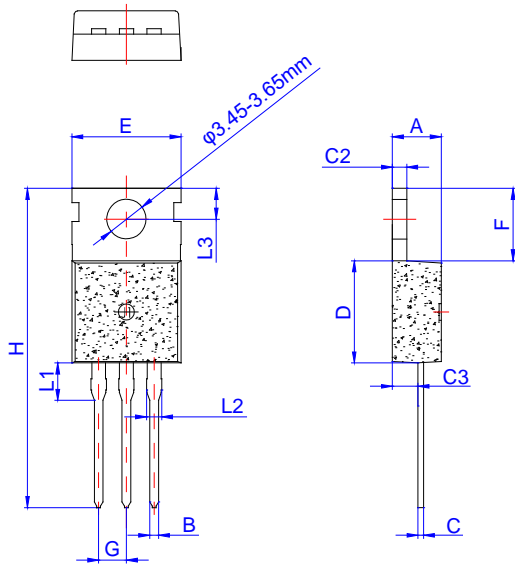
**ORDERING INFORMATION**

Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
JCT1225C	1200	40	TO-220C	50	Tube

**Document Revision History**

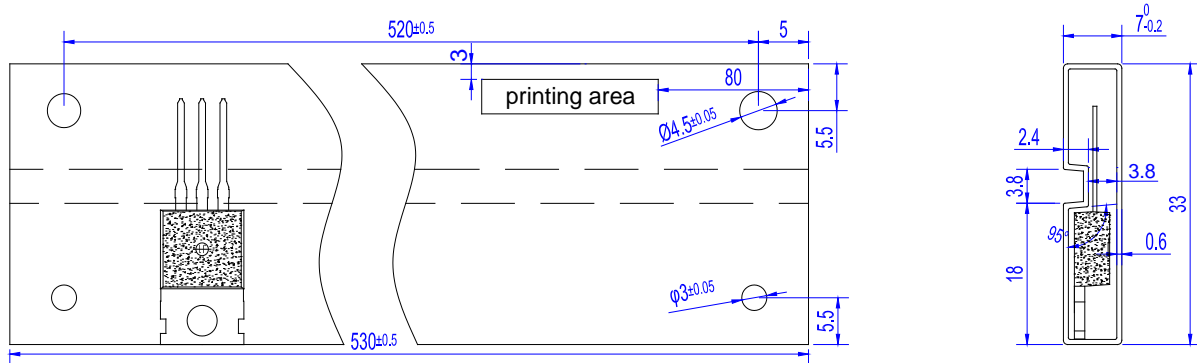
Date	Revision	Changes
Apr.13, 2023	A.1.0	Last update

PACKAGE MECHANICAL DATA




Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.70		0.90	0.028		0.035
C	0.45		0.60	0.018		0.024
C2	1.25		1.35	0.049		0.053
C3	2.20		2.60	0.087		0.102
D	8.90		9.90	0.350		0.390
E	9.90		10.3	0.390		0.406
F	6.30		6.90	0.248		0.272
G	2.40		2.70	0.094		0.106
H	28.0		29.8	1.102		1.173
L1	2.70		3.30	0.106		0.130
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116

DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-220C	TUBE	50	1,000	5,000

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